

**Damper diode
fast, high-voltage****BY359X-1500
BY359X-1500S****GENERAL DESCRIPTION**

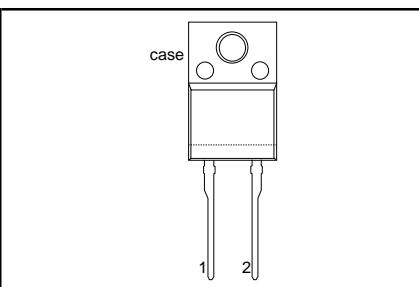
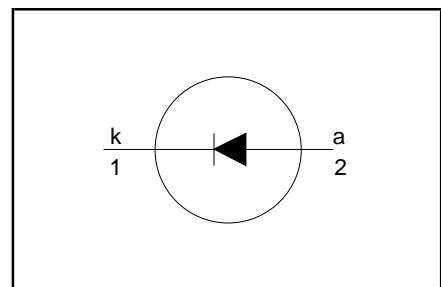
Glass-passivated double diffused rectifier diode in a plastic envelope featuring low forward voltage drop, fast reverse recovery and soft recovery characteristic. The device is intended for use in TV receivers and PC monitors.

QUICK REFERENCE DATA

SYMBOL	PARAMETER	MAX.	UNIT
V_{RRM}	Repetitive peak reverse voltage	1500	V
V_F	Forward voltage BY359X-1500	1.8	V
$I_{F(RMS)}$	BY359X-1500S	2.0	V
I_{FSM}	RMS forward current	15.7	A
t_{rr}	Non-repetitive peak forward current	60	A
	Reverse recovery time BY359X-1500	0.60	μ s
	BY359X-1500S	0.35	μ s

PINNING - SOD113

PIN	DESCRIPTION
1	cathode
2	anode
case	isolated

PIN CONFIGURATION**SYMBOL****LIMITING VALUES**

Limiting values in accordance with the Absolute Maximum System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V_{RSM}	Non-repetitive peak reverse voltage		-	1500	V
V_{RRM}	Repetitive peak reverse voltage		-	1500	V
V_{RWM}	Crest working reverse voltage		-	1300	V
$I_{F(peak)}$	Peak forward current	16-32kHz TV BY359X-1500 31-64kHz monitor BY359X-1500S	-	10	A
$I_{F(RMS)}$	RMS forward current	sinusoidal; $a = 1.57$	-	15.7	A
I_{FRM}	Repetitive peak forward current	$t = 10$ ms	-	60	A
I_{FSM}	Non-repetitive peak forward current	$t = 8.3$ ms	-	60	A
T_{stg}	Storage temperature	sinusoidal; $T_j = 150$ °C prior to surge; with reapplied $V_{RWM(max)}$	-40	150	°C
T_j	Operating junction temperature		-	150	°C

ISOLATION LIMITING VALUE & CHARACTERISTIC

$T_{hs} = 25$ °C unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V_{isol}	R.M.S. isolation voltage from both terminals to external heatsink	$f = 50-60$ Hz; sinusoidal waveform; R.H. ≤ 65% ; clean and dustfree	-		2500	V
C_{isol}	Capacitance from both terminals to external heatsink	$f = 1$ MHz	-	10	-	pF

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THERMAL RESISTANCES

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
$R_{th\ j-hs}$	Thermal resistance junction to heatsink	with heatsink compound	-	-	4.8	K/W
$R_{th\ j-a}$	Thermal resistance junction to ambient	without heatsink compound in free air.	-	-	55	K/W

STATIC CHARACTERISTICS

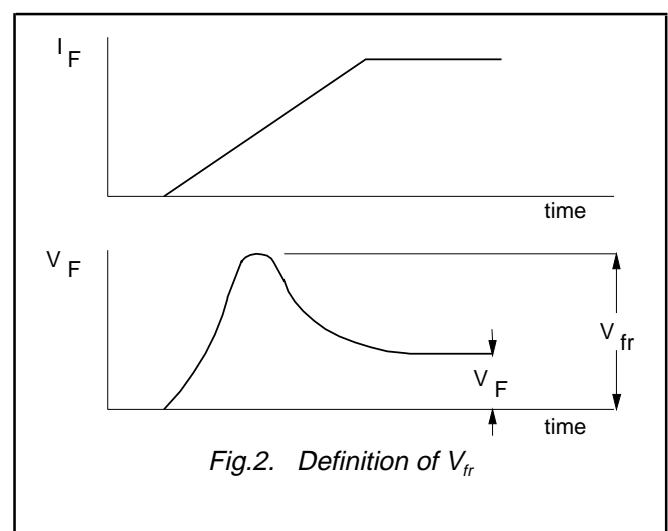
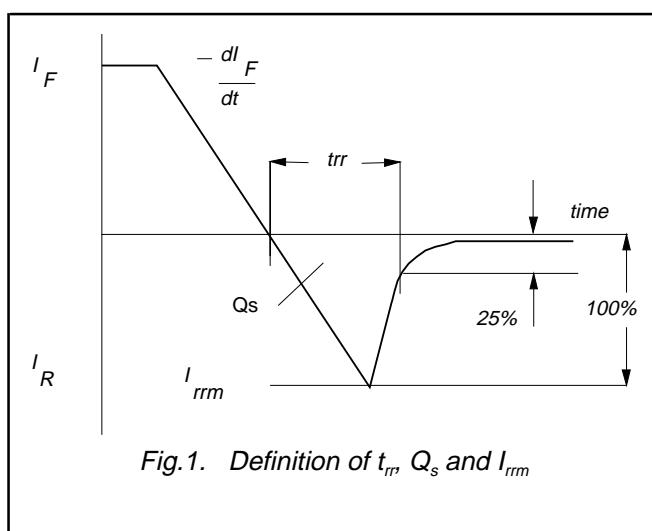
$T_j = 25^\circ\text{C}$ unless otherwise stated

SYMBOL	PARAMETER	CONDITIONS	BY359X-1500		BY359X-1500S		UNIT
			TYP.	MAX.	TYP.	MAX.	
V_F	Forward voltage	$I_F = 20\text{ A}$	1.3	1.8	1.5	2.0	V
	Reverse current	$I_F = 10\text{ A}; T_j = 150^\circ\text{C}$ $V_R = 1300\text{ V}$ $V_R = 1300\text{ V}; T_j = 100^\circ\text{C}$	1.00	1.5	1.25	1.75	μA
I_R		10	100	10	100	600	μA
		50	300	100	600		

DYNAMIC CHARACTERISTICS

$T_j = 25^\circ\text{C}$ unless otherwise stated

SYMBOL	PARAMETER	CONDITIONS	BY359X-1500		BY359X-1500S		UNIT
			TYP.	MAX.	TYP.	MAX.	
t_{rr}	Reverse recovery time	$I_F = 2\text{ A}; V_R \geq 30\text{ V}; -dI_F/dt = 20\text{ A}/\mu\text{s}$	0.47	0.60	0.28	0.35	μs
	Reverse recovery charge		1.6	2.0	0.70	0.95	μC
V_{fr}	Peak forward recovery voltage	$I_F = 10\text{ A}; dI_F/dt = 30\text{ A}/\mu\text{s}$	11.0	-	17.0	-	V



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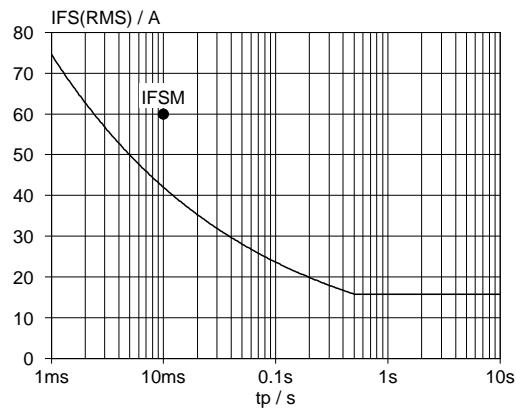


Fig.3. Maximum non-repetitive rms forward current.
 $I_F = f(t_p)$; sinusoidal current waveform; $T_j = 150^\circ\text{C}$ prior to surge with reapplied V_{RWM} .

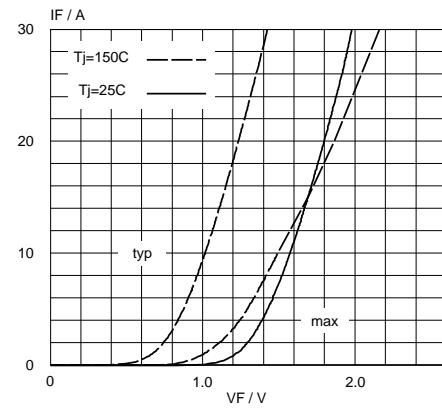


Fig.5. BY359X-1500 forward characteristic $I_F = f(V_F)$; parameter T_j

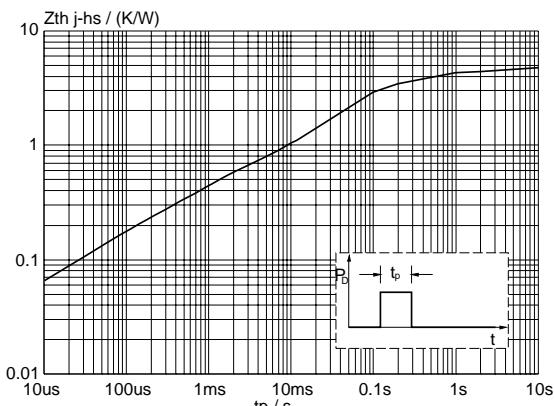


Fig.4. Transient thermal impedance $Z_{th} = f(t_p)$

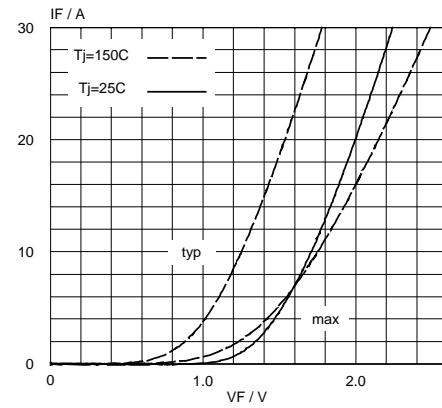


Fig.6. BY359X-1500S forward characteristic $I_F = f(V_F)$; parameter T_j

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MECHANICAL DATA

Dimensions in mm

Net Mass: 2 g

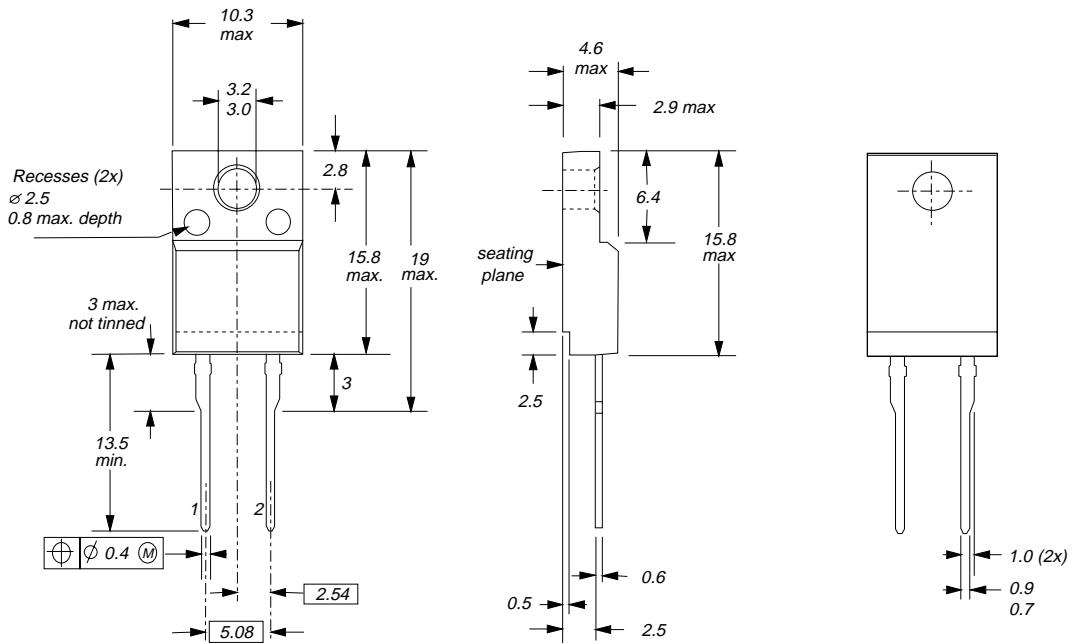


Fig.7. SOD113; The seating plane is electrically isolated from all terminals.

Notes

1. Refer to mounting instructions for F-pack envelopes.
2. Epoxy meets UL94 V0 at 1/8".